

Features

- 500-mA-Rated Collector Current(single output)
- Inputs Compatible With Various Types of Logic
- High-Voltage Outputs:50V
- High input voltage (up to 5.5V)
- Relay-Driver Applications

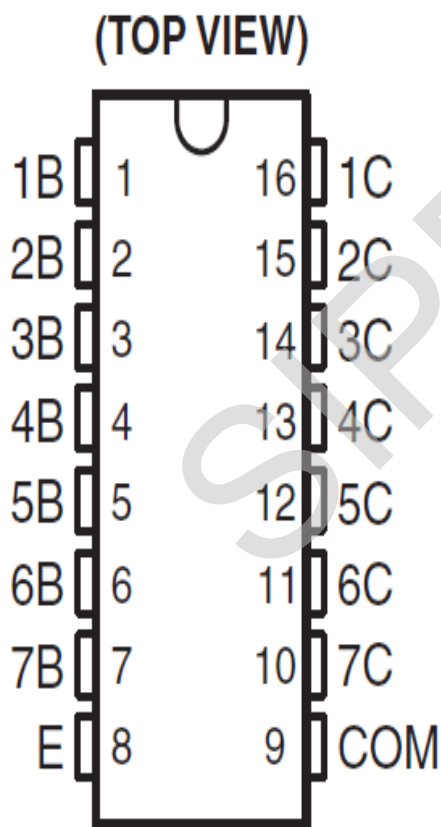
General Description

The ULN2003 is high-voltage high-current Darlington transistor arrays each containing seven open collector common emitter pairs. Each pair is rated at 500mA. Suppression diodes are included for inductive load driving, the inputs and outputs are pinned in opposition to simplify board layout.

These devices are capable of driving a wide range of loads including solenoids, relays, DC motors, LED displays, filament lamps, thermal print-heads and high-power buffers.

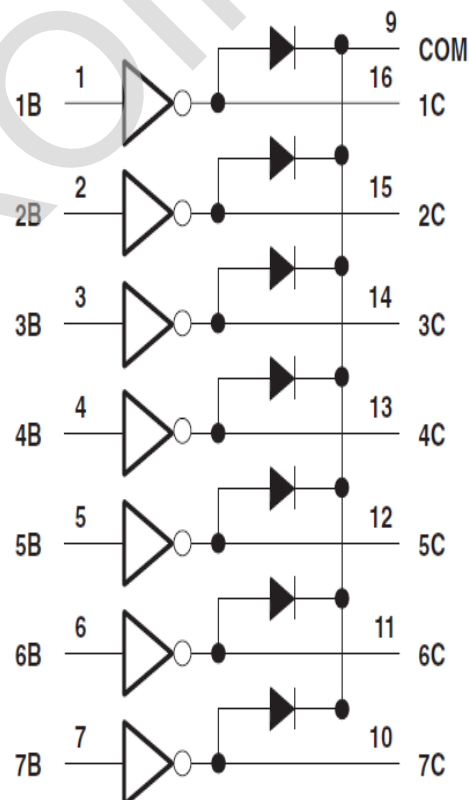
The ULN2003 is available in both a small outline 16-pin package (SOP16).

Pin Assignments



Connection Diagram

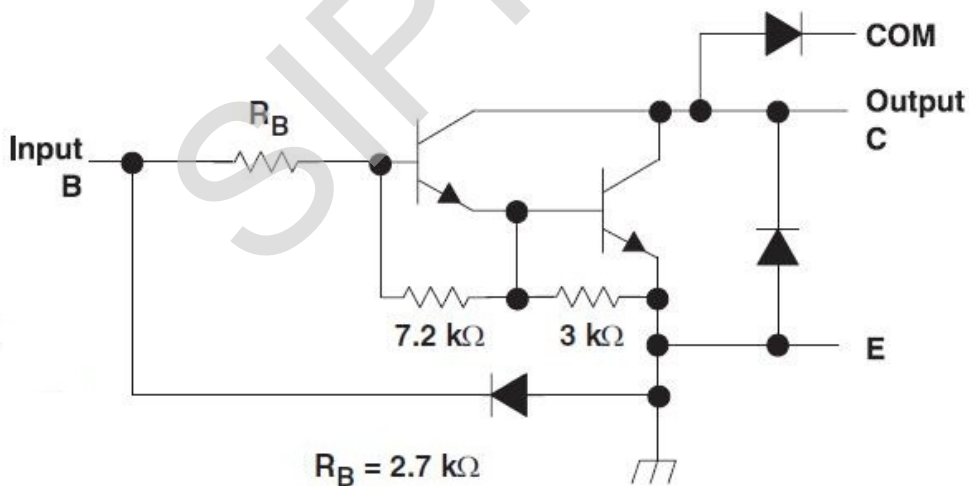
LOGIC DIAGRAM



Pin Descriptions

Pin Number	Pin Name	Function
1	1B	Input pair1
2	2B	Input pair1
3	3B	Input pair1
4	4B	Input pair1
5	5B	Input pair1
6	6B	Input pair1
7	7B	Input pair1
8	E	Common Emitter (ground)
9	COM	Common Clamp Diodes
10	7C	Output pair7
11	6C	Output pair6
12	5C	Output pair5
13	4C	Output pair4
14	3C	Output pair3
15	2C	Output pair2
16	1C	Output pair1

Functional Block Diagram



Note: All resistor values shown are nominal.

The collector-emitter diode is a parasitic structure and should not be used to conduct current. If the collector(s) go below ground an external Schottky diode should be added to clamp negative undershoots.

Absolute Maximum Ratings ⁽¹⁾

At 25°C free-air temperature (unless otherwise noted)

Symbol	Parameter		Min	Max	Unit
V _{CC}	Collector to emitter voltage			50	V
V _R	Clamp diode reverse voltage(2)			50	V
V _I	Input voltage(2)			30	V
I _{CP}	Peak collector current	See typical characteristics		500	mA
I _{OK}	Output clamp current			500	mA
I _{TE}	Total emitter-terminal current			-2.5	A
T _A	Operating free-air temperature range	ULN2003	-20	70	°C
θ _{JA}	Thermal Resistance Junction-to-Ambient(3)			63	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case(4)			12	
T _J	Operating virtual junction temperature			150	°C
T _{STG}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.
- (3) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $PD = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (4) Maximum power dissipation is a function of T_{J(max)}, θ_{JC}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $PD = (T_J(max) - T_A)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	Collector to Emitter voltage	-	50	V
T _A	Operating Ambient Temperature	40	+105	°C

Electrical Characteristics (TA = +25°C, unless otherwise specified)

Parameter		Test Figure	Test Conditions		ULN2003			Unit
					MIN	TYP	MAX	
V _{I(on)}	On-state input voltage	Figure 6	V _{CE} = 2 V	I _C = 200 mA	--	--	2.4	V
				I _C = 250 mA	--	--	2.7	
				I _C = 300 mA	--	--	3	
V _{CE(sat)}	Collector-emitter saturation voltage	Figure 5	I _I = 250 μA, I _C = 100 mA	--	0.9	1.1	V	
			I _I = 350 μA, I _C = 200 mA	--	1	1.3		
			I _I = 500 μA, I _C = 350 mA	--	1.2	1.6		
I _{CEX}	Collector cutoff current	Figure 1	V _{CE} = 50 V, I _I = 0	--	--	50	μA	
		Figure 2	V _{CE} = 50 V, T _A = +105°C, I _I = 0	--	--	100		
V _F	Clamp forward voltage	Figure 8	I _F = 350 mA	--	1.7	2	V	
I _{I(off)}	Off-state input current	Figure 3	V _{CE} = 50 V, I _C = 500 μA	50	65	--	μA	
I _I	Input current	Figure 4	V _I = 3.85 V	--	0.93	1.35	mA	
			V _I = 5 V	--	--	--		
			V _I = 12 V	--	--	--		
I _R	Clamp reverse current	Figure 7	V _R = 50 V		--	--	50	μA
				T _A = 70°C	--	--	100	
C _i	Input capacitance		V _I = 0, f = 1 MHz	--	15	25	pF	

Switching Characteristics (T_A = +25°C, unless otherwise specified)

Parameter		Test Conditions	ULN2003			UNIT
			MIN	TYP	MAX	
t _{PLH}	Propagation delay time, low- to high-level output	See Figure 9		0.25	1	μs
t _{PHL}	Propagation delay time, high- to low-level output	See Figure 9		0.25	1	μs
V _{OH}	High-level output voltage after switching	V _S = 50 V, I _O = 300 mA, See Figure 9	V _S -20			mV

Parameter Measurement Information

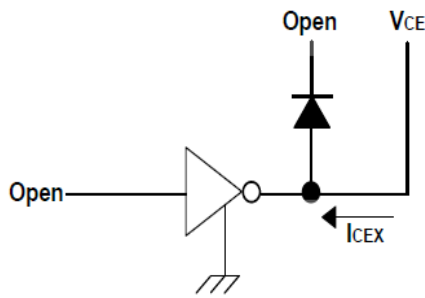


Fig.1 ICEX Test Circuit

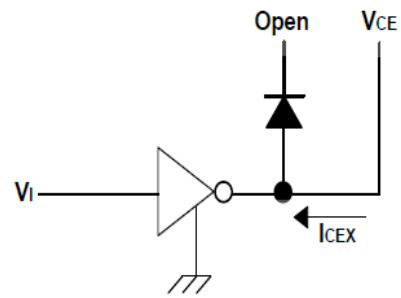


Fig.2 ICEX Test Circuit

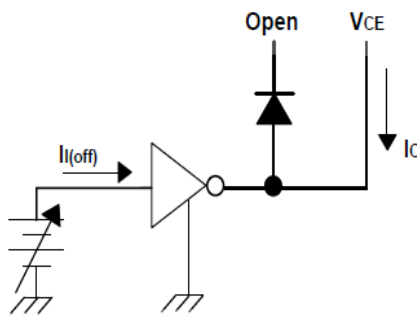


Fig.3 $I_{(off)}$ Test Circuit

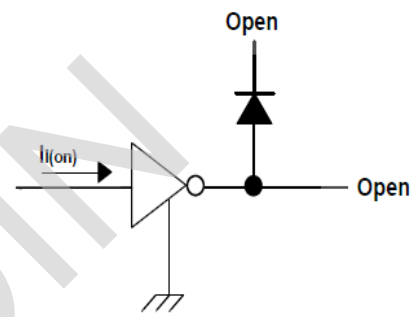


Fig.4 $I_{(on)}$ Test Circuit

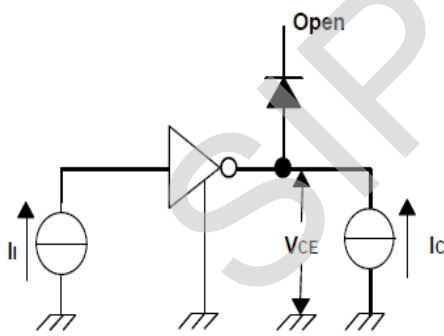


Fig. 5 h_{FE} , $V_{CE(sat)}$ Test Circuit

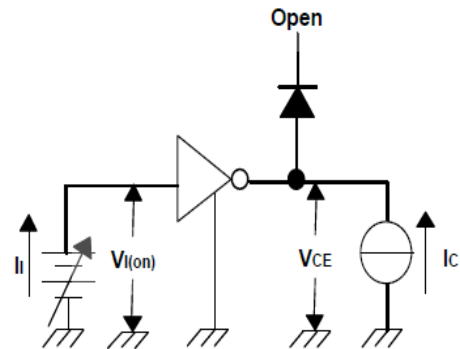


Fig. 6 $V_{(on)}$ Test Circuit

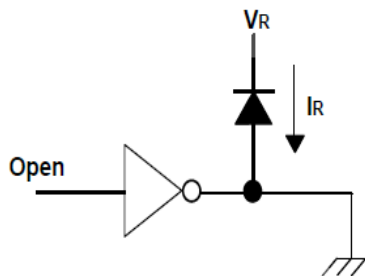


Fig. 7 I_R Test Circuit

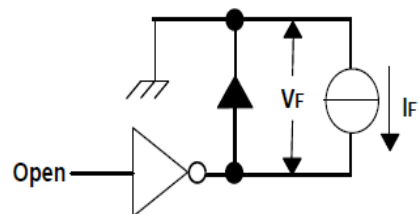


Fig. 8 V_F Test Circuit

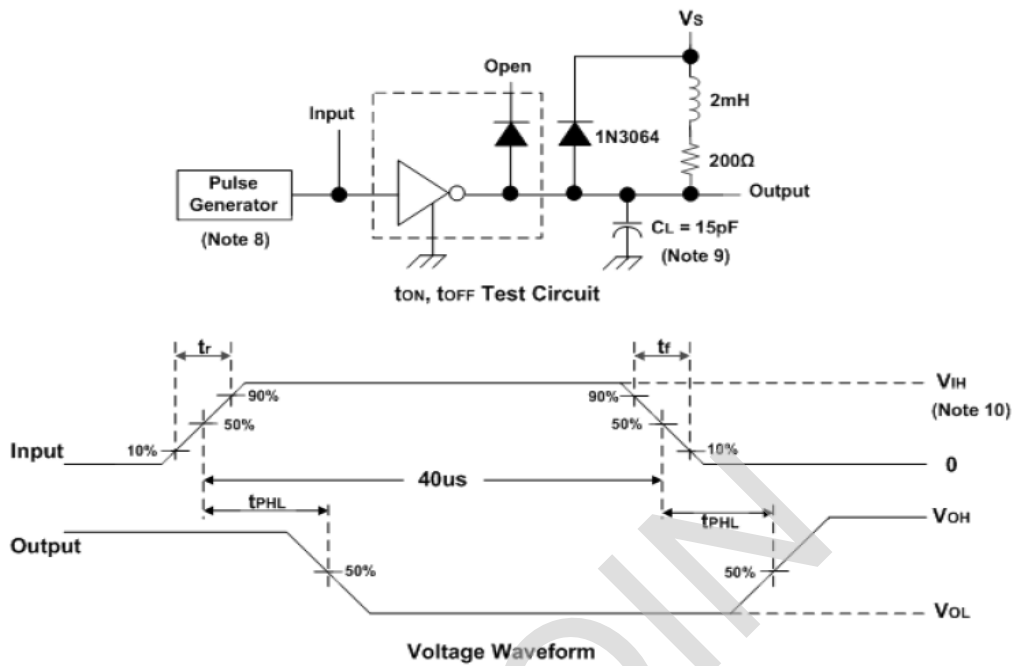
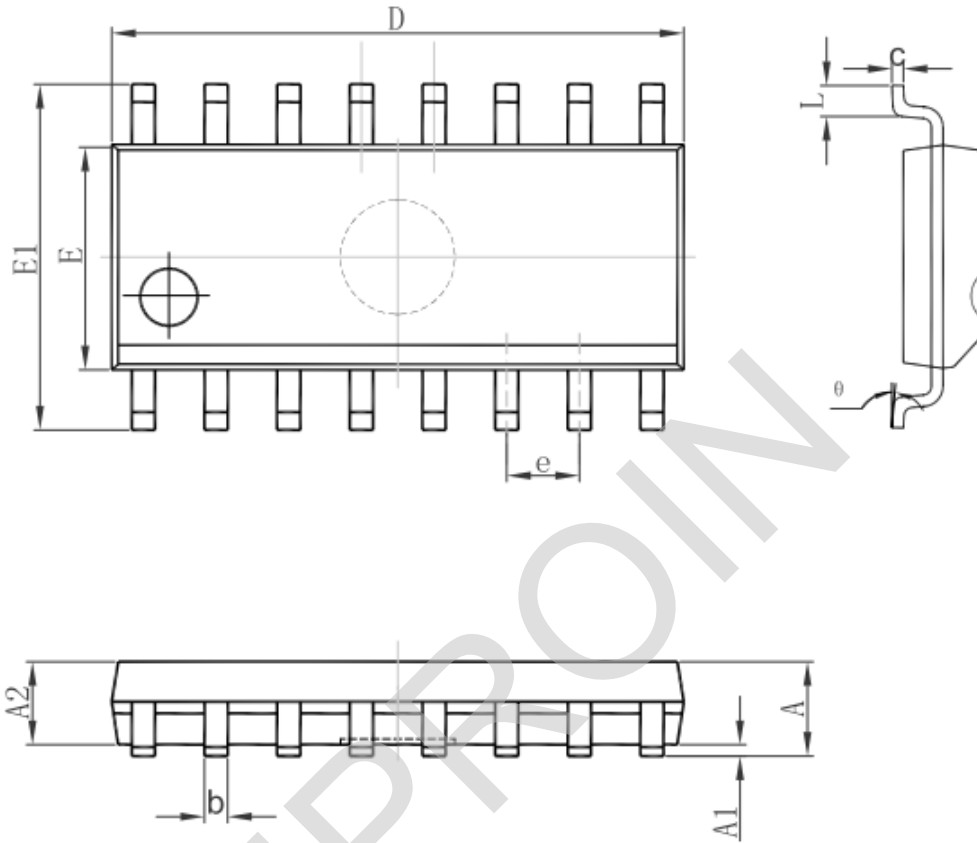


Fig. 9 Latch-Up Test Circuit and Voltage Waveform

- Notes:
8. The pulse generator has the following characteristics:
Pulse Width=12.5Hz, output impedance 50Ω, $t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$.
 9. C_L includes probe and jig capacitance.
 10. $V_{IH} = 3\text{V}$

Packaging Information
SOP16 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Darlington Transistors](#) category:

Click to view products by [Siproin](#) manufacturer:

Other Similar products are found below :

[281287X](#) [SMMBT6427LT1G](#) [2N7371](#) [BDV64B](#) [JANTXV2N6287](#) [028710A](#) [SMMBTA64LT1G](#) [2N6350](#) [2SB1214-TL-E](#)
[SMMBTA14LT1G](#) [SBSP52T1G](#) [NJVMJD117T4G](#) [Jantx2N6058](#) [2N6353](#) [LB1205-L-E](#) [500-00005](#) [2N6053](#) [NJVMJD112G](#) [Jan2N6350](#)
[Jantx2N6352](#) [Jantx2N6350](#) [BULN2803LVS](#) [ULN2001N](#) [2SB1383](#) [2SB1560](#) [2SB852KT146B](#) [TIP112TU](#) [TIP122TU](#) [BCV27](#) [MMBTA13-](#)
[TP](#) [MMBTA14-TP](#) [MMSTA28T146](#) [BSP50H6327XTSA1](#) [KSH122TF](#) [NTE2557](#) [NJVNJD35N04T4G](#) [TIP115](#) [MPSA29-D26Z](#) [MJD127T4](#)
[FJB102TM](#) [BCV26E6327HTSA1](#) [BCV46E6327HTSA1](#) [BCV47E6327HTSA1](#) [BSP61H6327XTSA1](#) [BU941ZPFI](#) [2SB1316TL](#) [2SD1980TL](#)
[NTE2350](#) [NTE245](#) [NTE246](#)